

REFAST: 106011001865NIP11 SUBSTRATEX000001

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	U	Inventor	Document	Issue	P	Title	Current	Current X	Retrieval	S	C	P	Image	Do	P
1	<input type="checkbox"/>	Sarayama	US 200400	2004	3	Production of a GaN bulk crystal subst	117/36			<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040	
2	<input type="checkbox"/>	Sarayama	US 659266	2003	3	Production of a GaN bulk crystal subst	117/68	117/13		<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 65926	
3	<input type="checkbox"/>	Kitaoka, Ya	US 200500	2005	1	Method of manufacturing Group III nitri	117/54			<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20050	
4	<input type="checkbox"/>	Kitaoka, Ya	US 200402	2004	3	Group III nitride crystals usable as gro	257/18	257/102		<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040	
5	<input type="checkbox"/>	Dwilinski, R	US 200402	2004	2	Substrate for epitaxy	117/84	117/104		<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040	
6	<input type="checkbox"/>	Kitaoka, Ya	US 200401	2004	2	Method of manufacturing group III nitr	257/10			<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040	
7	<input type="checkbox"/>	Kitaoka, Ya	US 200401	2004	2	Method of manufacturing Group III nitr	438/48	257/E21.1		<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040	
8	<input type="checkbox"/>	Kitaoka, Ya	US 200401	2004	1	Method of manufacturing group III nitr	117/2			<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040	
9	<input type="checkbox"/>	Iwata, Hiro	US 200401	2004	3	Group III nitride crystal, crystal growth	117/2			<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040	